

PRELIMINARY DATA SHEET

SKY77550 Tx Quad-Band / Rx Dual-Band BiFET iPAC[™] FEM for GSM / GPRS (824-915 MHz and 1710-1910 MHz)

Applications

- Dual-band cellular handsets encompassing
 - Class 4 GSM850/900
 - DCS1800/PCS1900
 - Class 12 GPRS multi-slot operation

Features

- · High efficiency
 - 42% (GSM850)
 - 42% (GSM900)
 - 42% (DCS1800
 - 41% (PCS1900)
- Low transmit supply current
 - 1.36 A (GSM850)
 - 1.36 A (GSM900)
 - 0.86 A (DCS1800)
 - 0.88 A (PCS1900)
- Internal ICC sense resistor for iPAC
- · Closed loop iPAC
- 50 Ω matched Input/Output
- Tx–VCO-to-antenna and antenna-to-Rx-SAW filter RF interface
- RF switch affords high linearity, low insertion loss, and 0 V DC on Rx ports
- Small, low profile package
 - 6 mm x 6 mm x 0.9 mm
 - 28-pad configuration



Skyworks Green™ products are RoHS (Restriction of Hazardous Substances)compliant, conform to the EIA/EICTA/JETA Joint Industry Guide (JIG) Level A guidelines, are halogen free according to IEC-61249-2-21, and contain < 1,000 ppm antimony trioxide in polymeric materials.

Description

SKY77550 is a transmit and receive Front-End Module (FEM) with Integrated Power Amplifier Control (iPAC[™]) designed in a low profile, compact form factor for dual-band cellular handsets comprising GSM850/900 and DCS1800/PCS1900 operation. The SKY77550 offers a complete Transmit VCO-to-Antenna and Antenna-to-Receive SAW filter solution. The FEM also supports Class 12 General Packet Radio Service (GPRS) multi-slot operation.

The module consists of a GSM850/900 PA block and a DCS1800/PCS1900 PA block, impedancematching circuitry for 50 ohm input and output impedances, Tx harmonics filtering, high linearity / low insertion loss RF switch, and a Power Amplifier Control (PAC) block with internal current sense resistor. The two Heterojunction Bipolar Transistor (HBT) PA blocks, a BiFET PAC and switch control circuit are fabricated onto a single Gallium Arsenide (GaAs) die. One PA block supports the GSM850/900 bands and the other PA block supports the DCS1800/PCS1900 bands. Both PA blocks share common power supply pads to distribute current. The output of each PA block and the outputs to the two receive pads are connected to the antenna pad through an RF switch. The GaAs die, Switch die and passive components are mounted on a multi-layer laminate substrate. The assembly is encapsulated with plastic overmold.

Band selection and control of transmit and receive are performed using four external control pads. Refer to the block diagram in Figure 1 below. The band select pad, BS, selects GSM850, GSM900, DCS, and PCS modes of operation. Transmit enable TxEN controls receive or transmit mode of the RF switch (Tx = logic 1). Proper timing between transmit enable TxEN and Analog Power Control VRAMP allows for high isolation between the antenna and Tx–VCO while the VCO is being tuned prior to the transmit burst.

The SKY77550 is compatible with logic levels from 1.2 V to 2.9 V for BS, TxEN, and VSW_EN pads.

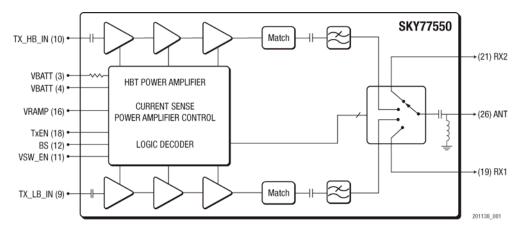


Figure 1. SKY77550 Functional Block Diagram

Electrical Specifications

The following tables list the electrical characteristics of the SKY77550 Front-End Module. The absolute maximum ratings and recommended operating conditions for the SKY77550 are listed in Table 1 and Table 2, respectively. Table 3 specifies the mode control logic and Table 4 contains the electrical characteristics of

SKY77550 Tx QUAD-BAND / Rx DUAL-BAND BIFET iPAC[™] FEM for GSM / GPRS (824-915 MHz and 1710-1910 MHz)

the SKY77550 for modes GSM850/900 and DCS1800/PCS1900. Figure 2 presents an application schematic for the SKY77550.

The SKY77550 is a static-sensitive electronic device and should not be stored or operated near strong electrostatic fields. Detailed information on device dimensions, pad descriptions, packaging and handling can be found in later sections of this data sheet.

Table 1. SKY77550 Absolute Maximum Ratings

Parameter	Minimum	Nominal	Maximum	Unit
Input Power (PIN)	—	3	15	dBm
Supply Voltage (Vcc), Standby VRAMP $\leq 0.3 \text{ V}$ Vsw_en $\leq 0.5 \text{ V}$	_	3.5	7	V
Control Voltage (VRAMP)	-0.5	1.6	Vcc_max – 0.2 V (See Table 4)	V
Storage Temperature	-55	+25	+150	°C

¹ No damage assuming only one parameter is set at limit with all other parameters set at nominal value.

Table 2. SKY77550 Recommended Operating Conditions

Parameter		Minimum	Nominal	Maximum	Unit
Supply Voltage (Vcc)		3.1	3.5	4.8	V
Supply Current (Icc)		0	—	1.8	А
Operating Case Temperature (TCASE) ¹	1-Slot (12.5% duty cycle)	-20	—	+85	°C
	2-Slot (25% duty cycle)	-20	—	+85	
	3-Slot (37.5% duty cycle) ²	-20	—	+85	
	4-Slot (50% duty cycle) ²	-20	_	+85	

¹ Case Operating Temperature refers to the temperature of the GROUND PAD on the underside of the package.

² Max. output power must be reduced by 6 dB to support 3-slot and 4-slot operation.

Table 3. SKY77550 Mode Control Logic

		Input Control Bits					
Mode	VSW_EN	TxEN	BS				
STANDBY	0	0	0				
Rx1 ¹	1	0	0				
Rx2 ¹	1	0	1				
Tx_LB	1	1	0				
Tx_HB	1	1	1				

¹ Rx1 and Rx2 are broadband receive ports and each supports the GSM850, GSM900, DCS, and PCS bands.

			General				
Parameter		Symbol	Test Condition	Minimum	Typical	Maximum	Unit
Supply Voltage		Vcc	_	3.1	3.5	4.8	۷
Power Control Impedance		Zvramp	—	_	120	_	kΩ
/SW_EN Control Voltage LOW		Vsw_en_low	—	-0.1	_	0.3	۷
	HIGH	Vsw_en_high		1.2		2.9	
VSW_EN Current		Ivsw_en	—	_	_	25	μA
Band Select Control Voltage LOW		Vbs_low	—	-0.1	_	0.3	۷
	HIGH	Vbs_high		1.2	_	2.9	
Band Select Current		IBS	—	_	_	25	μA
TxEN Control Voltage	LOW	VTXEN_LOW	—	-0.1	_	0.3	۷
	HIGH	VTxen_high		1.2		2.9	
TxEN Control Current		Itxen	—	_	_	60	μA
Leakage Current Standby Mode		las	$\begin{array}{l} 3.1 \ V \leq Vcc \leq 4.2 \ V \\ Vsw_en = Vsw_en_low \\ Vramp \leq 0.1 \ V \\ TxEN \leq TxEN_low \\ BS \leq VBs_low \\ MODE < Vmode_low \\ Tcase = +25 \ ^{\circ}C \\ Pin \leq -60 \ dBm \end{array}$		30	50	μA
R	eceive Mode	IQRX	$\label{eq:VCC} \begin{array}{l} V_{CC} \leq 4.2 \ V \\ 1.8 \ V \leq V_{SW}_{EN} \leq 2.5 \ V \\ V_{RAMP} \leq 0.1 \ V \\ TxEN \leq TxEN_{_LOW} \\ MODE < V_{MODE}_{_LOW} \\ MODE < V_{MODE}_{_LOW} \\ TcAse = +25 \ ^{\circ}C \\ P_{IN} \leq -60 \ dBm \end{array}$		200	250	

Table 4. SKY77550 Electrical Specifications¹

Unless specified otherwise:

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TCASE = -20 °C to max. operating temperature (see Table 2); RL = 50 Ω ; pulsed operation with pulse width \leq 1154 µs and duty cycle \leq 2:8; 3.1 V \leq VCC \leq 4.8 V.

	GSM850 (Tx_LL	8) Mode (ƒ = 824 MHz to 849 MHz, −1 dBm ≤ Pııı ≤ 5 dBr	n)			
Parameter	Symbol	Test Condition	Minimum	Typical	Maximum	Unit
Frequency Range	f	_	824		849	MHz
Input Power	Pin	_	-1	_	5	dBm
Analog Power Control Voltage	Vramp	_	0.2		1.6	V
Power Added Efficiency	PAE	Vcc = 3.5 V Pout = 33 dBm PiN = 3 dBm duty cycle 1:8 TCASE = $+25 \text{ °C}$	39	42	_	%
Supply Current @ Rated Power	lcc_33 dBm	Vcc = 3.5 V Pout = 33 dBm PiN = 3 dBm duty cycle 1:8 Tcase = $+25 \text{ °C}$	_	1.36	1.46	А
	lcc_29 dBm	Vcc = 3.5 V Pout = 29 dBm PiN = 3 dBm duty cycle 1:8 TCASE = $+25 \text{ °C}$	_	770	_	mA
Supply Current @ Minimum Power	lcc_5 dBm	Vcc = 3.5 V Pout = 5 dBm PiN = 3 dBm duty cycle 1:8 Tcase = $+25 \text{ °C}$	_	70	85	mA
Harmonics	2fo to 13fo	$\begin{array}{l} BW = 3 \mbox{ MHz} \\ 5 \mbox{ dBm} \leq Pout \leq 33 \mbox{ dBm} \\ V_{RAMP} \mbox{ controlled}^2 \end{array}$	_	-40	-33	dBm
Mismatch Harmonics	2fo to 7fo	BW = 3 MHz VRAMP = Max VRAMP4 VBATT = 3.5 V VSWR = 3:1 all phases TCASE = +25 °C	_	_	-33	
Output Power	Роит	Vcc = 3.5 V Tcase = +25 °C PiN = -1 dBm	33.0	33.7		dBm
	POUT_MAX LOW VOLTAGE	$\begin{array}{l} \mbox{Vcc} = 3.1 \ \mbox{V} \\ \mbox{Vramp} = \ \mbox{Max} \ \mbox{Vramp}^4 \\ -20 \ \ \mbox{C} \le \ \mbox{Tcase} \le +85 \ \ \mbox{C} \\ \mbox{Pin} = -1 \ \ \mbox{dBm} \end{array}$	30.5	32.0		
	POUT_MAX HIGH VOLTAGE	$Vcc = 4.8 V$ $VRAMP = Max VRAMP^{4}$ $-20 °C \le TCASE \le +85 °C$ $PIN = -1 dBm$	30.5	34.5	_	
Input VSWR	ΓIN	5 dBm \leq Pout \leq 33 dBm VRAMP controlled ²	—	1.5:1	2.5:1	
Forward Isolation ³	Pout_rx	Pin = 5 dBm Vramp ≤ 0.1 V Vsw_en = Vsw_en_high TxEN = Vtxen_Low Rx1 Mode	_	55	-45	dBm
	Pout_enabled_tx	$\label{eq:Pin} \begin{array}{l} Pin = 5 \ dBm \\ Vramp \leq 0.1 \ V \\ Vsw_en = Vsw_en_high \\ TxEN = Vtxen_high \end{array}$	—	-25	-5	

Table 5. SKY77550 Electrical Specifications¹ (1 of 2)

		Table 5	SKY77550 Electrical Specifications' (2 of 2)				
		[continued] GSM850	(Tx_LB) Mode ($f = 824$ MHz to 849 MHz, -1 dBm \leq Pm	<i>i ≤ 5 dBm)</i>			
Ра	arameter	Symbol	Test Condition	Minimum	Typical	Maximum	Unit
Coupling of GSM to Rx ⁵ Output pa	850/900 Tx Output (<i>f</i> ₀) d ⁴	CGHI_Tx-Rx_f0	$5 \text{ dBm} \le P_{\text{OUT}} \le 33 \text{ dBm}$	—	-5	0	dBm
Coupling of GSM (2 <i>f</i> 0, 3 <i>f</i> 0) to Rx ⁵	850/900 Tx Output Output pad ⁴	CGHI_Tx-DCS_Rx	$5 \text{ dBm} \le P_{\text{OUT}} \le 33 \text{ dBm}$	—	-45	-36	dBm
Spurious		Spur	All combinations of the following parameters: $V_{RAMP} = controlled^2$ $P_{IN} = min. to max.$ $3.1 V \le Vcc \le 4.8 V$ $-20 \ ^{\circ}C \le T_{CASE} \le +85 \ ^{\circ}C$ Load VSWR = 12:1, all phase angles	No parasitic oscillation > –35 dBn		Bm	
Load Mismatch		Load	All combinations of the following parameters: $V_{RAMP} = controlled^2$ $P_{IN} = min. to max.$ $3.1 V \le Vcc \le 4.8 V$ $-20 \ ^{\circ}C \le T_{CASE} \le +85 \ ^{\circ}C$ Load VSWR = 20:1, all phase angles	No mo	No module damage or permanent degradation		
Rx Band Spurious		Rx_spur	At $f_0 + 20$ MHz (869 MHz to 894 MHz) RBW = 100 kHz Vcc = 3.5 V TCASE = +25 °C 5 dBm \leq Pout \leq 33 dBm	_	-84	-83	dBm
			At 1930 MHz to 1990 MHz RBW = 100 kHz Vcc = 3.5 V TCASE = +25 °C 5 dBm ≤ Pout ≤ 33 dBm	— — — — — — — — — — — — 4		-84	
Power Control Dy	ynamic Range	PCdr	_	30	50		dB
Power Control Variation	Control Level 5	PCv	VBATT = 3.5 V Pout = 33 dBm TCASE = +25 °C	-1.5	_	1.5	dB
			Роит = 33 dBm	-2.0		2.0	
	Control Level 6-15		$\label{eq:VBATT} \begin{array}{l} V_{BATT} = 3.5 \text{ V} \\ 13 \text{ dBm} \leq Pout \leq 31 \text{ dBm} \\ T_{CASE} = +25 \ ^{\circ}C \end{array}$	-2.5	_	2.5	
			$13 \text{ dBm} \le \text{Pout} \le 31 \text{ dBm}$	-3.5	_	3.5	
	Control Level 16-19		VBATT = 3.5 V 5 dBm ≤ Pout ≤ 11 dBm TCASE = +25 °C	-4.5		4.5	
			5 dBm \leq Pout \leq 11 dBm	-5.5	_	5.5	
Power Control Sl	ope	PCs	5 dBm to 33 dBm	_		250	dB/V
		GSM	1850 RECEIVE (f = 869 MHz to 894 MHz) Rx Mode				
Pa	arameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Frequency Range	e	f		869		894	MHz
Insertion Loss, Al	NT to Rx ^{5,3}	IL_Rx ⁵	$T_{CASE} = +25 \ ^{\circ}C$		1.0	1.3	dB
VSWR ANT, Rx ^{5,3}	3	ΓΙΝ, ΓΟυτ	_	_	1.2:1	1.5:1	

Table 5. SKY77550 Electrical Specifications¹ (2 of 2)

¹ Unless specified otherwise:

TCASE = -20 °C to max. operating temperature (see Table 2); RL = 50 Ω ; pulsed operation with pulse width \leq 1154 µs and duty cycle \leq 2:8; 3.1 V \leq VCC \leq 4.8 V.

 2 $\,$ VRAMP is calibrated to each PCL at TCASE = +25 °C, VBATT = 3.5 V, PIN = 3 dBm, 50 Ω load.

 3 $\,$ Terminate all unused RF ports with 50 Ω loads

 4 $\,$ Max VRAMP = VRAMP @ POUT =33 dBm, 50 Ω load, TCASE = +25 °C, VBATT = 3.5 V, PIN = 3 dBm $\,$

⁵ Rx1 and Rx2 are broadband receive ports and each supports the GSM850, GSM900, DCS, and PCS bands.

	GSM900 (Tx_LL	3) Mode (ƒ = 880 MHz to 915 MHz, −1 dBm ≤ Pix ≤ 5	5 dBm)			
Parameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Frequency Range	f		880	_	915	MHz
Input Power	Pin	_	-1	_	5	dBm
Analog Power Control Voltage	Vramp	_	0.2	_	1.6	V
Power Added Efficiency	PAE	Vcc = 3.5 V Pout = 33 dBm PiN = 3 dBm duty cycle 1:8 TCASE = $+25 \text{ °C}$	39	42	_	%
Supply Current @ Rated Power	lcc_33 dBm	Vcc = 3.5 V Pout = 33 dBm PiN = 3 dBm duty cycle 1:8 Tcase = $+25 \text{ °C}$	_	1.36	1.46	A
	lcc_29 dBm	Vcc = 3.5 V Pout = 29 dBm PiN = 3 dBm duty cycle 1:8 TCASE = $+25 \text{ °C}$	_	750	_	mA
Supply Current @ Minimum Power	lcc_5 dBm	Vcc = 3.5 V Pout = 5 dBm PiN = 3 dBm duty cycle 1:8 TCASE = $+25 \text{ °C}$	-	70	85	mA
Harmonics	2fo to 13fo	$\begin{array}{l} BW=3\ MHz\\ 5\ dBm\leqPout\leq33\ dBm\\ VRAMP\ controlled^2 \end{array}$		-40	-33	dBm
Mismatch Harmonics	2fo to 7fo	BW = 3 MHz $V_{RAMP} = Max V_{RAMP}^4$ $V_{BATT} = 3.5 V$ VSWR = 3:1 all phases $T_{CASE} = +25 °C$	_	_	-33	dBm
Output Power	Роит	Vcc = 3.5 V Tcase = +25 °C PiN = -1 dBm	33.0	33.7	—	dBm
	POUT_MAX LOW VOLTAGE	$\label{eq:Vcc} \begin{array}{l} Vcc = 3.1 \ V \\ Vramp = Max \ Vramp^4 \\ -20 \ ^\circC \leq Tcase \leq +85 \ ^\circC \\ Pin = -1 \ dBm \end{array}$	30.5	32.0	-	
	POUT_MAX HIGH VOLTAGE	$V_{CC} = 4.8 V$ $V_{RAMP} = Max V_{RAMP}^4$ $-20 °C \le T_{CASE} \le +85 °C$ $P_{IN} = -1 dBm$	30.5	34.5	_	
Input VSWR	ΓIN	Pout = 5 dBm to 33 dBm Vramp controlled ²	—	1.5:1	2.5:1	

Table 6. SKY77550 Electrical Specifications¹ (1 of 3)

	[continued] GSM90	D (Tx_LB) Mode (f = 880 MHz to 915 MHz, −1 dBm ≤ Pl	w <i>≤5 dBm)</i>			
Parameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Forward Isolation ³	Pout_rx	$\begin{array}{l} {\sf Pin}=5\;dBm\\ {\sf Vramp}\leq 0.1\;V\\ {\sf Vsw_en}={\sf Vsw_en_high}\\ {\sf TxEN}={\sf Vtxen_low}\\ {\sf Rx1}\;{\sf Mode} \end{array}$	_	-55	-45	dBm
	Pout_enabled_tx	$ \begin{array}{l} {\sf Pin}=5 \; dBm \\ {\sf Vramp} \leq 0.1 \; V \\ {\sf Vsw_en}={\sf Vsw_en_high} \\ {\sf TxEN}={\sf Vtxen_high} \end{array} $	_	-25	-5	
Coupling of GSM850/900 Tx Output (for the transformation of trans) CGHI_Tx-Rx_f0	$5 \text{ dBm} \le Pout \le 33 \text{ dBm}$	—	-5	0	dBm
Coupling of GSM850/900 Tx Output $(2f_0, 3f_0)$ to Rx^5 Output pad ³	CGHI_Tx_Rx ⁵	$5 \text{ dBm} \le Pout \le 33 \text{ dBm}$	—	-45	-36	dBm
Spurious	Spur	All combinations of the following parameters: $V_{RAMP} = controlled^2$ $P_{IN} = min. to max.$ $3.1 V \le Vcc \le 4.8 V$ $-20 °C \le T_{CASE} \le +85 °C$ Load VSWR = 12:1, all phase angles	No para	No parasitic oscillation > –36 dBn		
Load Mismatch	Load	All combinations of the following parameters: $V_{RAMP} = controlled^2$ $P_{IN} = min. to max.$ $3.1 V \le Vcc \le 4.8 V$ $-20 \text{ °C} \le T_{CASE} \le +85 \text{ °C}$ Load VSWR = 20:1, all phase angles	No mo	No module damage or permanen degradation		ent
Rx Band Spurious	Rx_spur	At $f_0 + 20$ MHz (935 MHz to 960 MHz) RBW = 100 kHz Vcc = 3.5 V TCASE = +25 °C 5 dBm \leq Pout \leq 33 dBm	_	-84	-83	dBm
		At $f_0 + 10$ MHz (925 MHz to 935 MHz) RBW = 100 kHz Vcc = 3.5 V TCASE = +25 °C 5 dBm \leq Pout \leq 33 dBm	-	-80	-76	
		At 1805 MHz to 1880 MHz RBW = 100 kHz Vcc = 3.5 V Tcase = +25 °C $5 \text{ dBm} \le Pout \le 33 \text{ dBm}$	—	-101	-84	
Power Control Dynamic Range	PCDR	_	30	50	_	dB
Power Control Control Level 5 Variation	PCv	VBATT = 3.5 V Pout = 33 dBm TCASE = +25 °C	-1.5		1.5	dB
	_	Pout = 33 dBm	-2.0	—	2.0	
Control Level 6-15		$\label{eq:VBATT} \begin{array}{l} VBATT = 3.5 \text{ V} \\ 13 \text{ dBm} \leq Pout \leq 31 \text{ dBm} \\ TCASE = +25 \ ^{\circ}C \end{array}$	-2.5	—	2.5	
		$13 \text{ dBm} \le Pout \le 31 \text{ dBm}$	-3.5	—	3.5	1
Control Level 16-19		$\label{eq:VBATT} \begin{array}{l} VBATT = 3.5 \text{ V} \\ 5 \text{ dBm} \leq Pout \leq 11 \text{ dBm} \\ TCASE = +25 \ ^\circC \end{array}$	-4.5		4.5	
		$5 \text{ dBm} \le P_{\text{OUT}} \le 11 \text{ dBm}$	-5.5		5.5	1
Power Control Slope	PCs	5 dBm to 33 dBm			250	dB/V

Table 6. SKY77550 Electrical Specifications¹ (2 of 3)

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Table 6. SKY77550 Electrical Specifications¹ (3 of 3)

GSM900 RECEIVE (f = 925 MHz to 960 MHz) Rx Mode						
Parameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Frequency Range	f	_	925	_	960	MHz
Insertion Loss, ANT to Rx ^{5,3}	IL_Rx ⁵	TCASE = +25 °C	_	1.0	1.3	dB
VSWR ANT, Rx ^{5,3}	ΓιΝ, ΓΟυτ	—	—	1.2:1	1.5:1	

¹ Unless specified otherwise:

TCASE = -20 °C to max. operating temperature (see Table 2); RL = 50Ω ; pulsed operation with pulse width $\leq 1154 \mu$ s and duty cycle $\leq 2:8$; $3.1 V \leq VCC \leq 4.8 V$.

 2 $\,$ VRAMP is calibrated to each PCL at TCASE = +25 °C, VBATT = 3.5 V, PIN = 3 dBm, 50 Ω load.

 3 $\,$ Terminate all unused RF ports with 50 Ω loads

 4 $\,$ Max VRAMP = VRAMP @ POUT =33 dBm, 50 Ω load, TCASE +25 °C, VBATT = 3.5 V, PIN = 3 dBm $\,$

⁵ Rx1 and Rx2 are broadband receive ports and each supports the GSM850, GSM900, DCS, and PCS bands.

	DCS1800 (Tx_	HB) Mode ($f = 1710$ MHz to 1785 MHz, -1 dBm \leq Pin \leq 5 d	Bm)			
Parameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Frequency Range	f	_	1710	_	1785	MHz
Input Power	Pin	—	-1	_	5	dBm
Analog Power Control Voltage	VRAMP	—	0.2	_	1.6	۷
Power Added Efficiency	PAE	Vcc = 3.5 V Pout = 31 dBm PiN = 3 dBm duty cycle 1:8 TCASE = $+25 \text{ °C}$	37	42	_	%
Supply Current @ Rated Power	lcc_31 dBm	$V_{CC} = 3.5 V$ $P_{OUT} = 31 \text{ dBm}$ $P_{IN} = 3 \text{ dBm}$ $duty cycle 1:8$ $T_{CASE} = +25 \text{ °C}$	_	0.86	0.97	A
	lcc_28 dBm	Vcc = 3.5 V Pout = 28 dBm PiN = 3 dBm duty cycle 1:8 TCASE = $+25 \text{ °C}$	-	630	-	mA
Supply Current @ Minimum Power	lcc_0 dBm	Vcc = 3.5 V $Pout = 0 dBm$ $PiN = 3 dBm$ $duty cycle 1:8$ $Tcase = +25 °C$	-	40	55	mA
Harmonics	2fo to 7fo	$\begin{array}{l} BW = 3 \mbox{ MHz}, \\ 0 \mbox{ dBm} \leq Pout \leq 31 \mbox{ dBm} \\ V_{RAMP} \mbox{ controlled}^2 \end{array}$	_	-40	-33	dBm
Mismatch Harmonics	2f0, 3f0	BW = 3 MHz $V_{RAMP} = Max V_{RAMP}^4$ $V_{BATT} = 3.5 V$ VSWR = 3:1 all phases $T_{CASE} = +25 °C$	_	_	-33	dBm

Table 7. SKY77550 Electrical Specifications ¹ (1 of 3)

	[continued] <i>DCS1800 (1</i>	x_HB) Mode (f = 1710 MHz to 1785 MHz, -1 dBm \leq P	'ıı ≤ 5 dBm <i>)</i>				
Parameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units	
Output Power	Роит	$V_{CC} = 3.5 V$ $T_{CASE} = +25 °C$ $P_{IN} = -1 dBm$	31.0	32.0		dBm	
	POUT _MAX LOW VOLTAGE	$V_{CC} = 3.1 V$ $V_{RAMP} = MAX V_{RAMP}^4$ $-20 \circ C \leq T_{CASE} \leq +85 \circ C$ $P_{IN} = -1 dBm$	28.5	30.0	_		
	POUT _MAX HIGH VOLTAGE	$V_{CC} = 4.8 V$ $V_{RAMP} = Max V_{RAMP}^4$ $-20 \circ C \leq T_{CASE} \leq +85 \circ C$ $P_{IN} = -1 dBm$	28.5	32.5	_		
Input VSWR	ΓIN	$0 \text{ dBm} \le P_{OUT} \le 31 \text{ dBm}$ VRAMP controlled ²	—	1.5:1	2.5:1		
Forward Isolation ³	Pout Rx	$\label{eq:Pin} \begin{array}{l} Pin = 5 \ dBm \\ Vramp \leq 0.1 \ V \\ Vsw_en = Vsw_en_high \\ TxEN = Vtxen_low \\ Rx2 \ Mode \end{array}$	_	-65	-53	dBm	
	Pout_enabled_tx	$\label{eq:Pin} \begin{array}{l} Pin = 5 \ dBm \\ Vramp \leq 0.1 \ V \\ Vsw_en = Vsw_en_high \\ TxEN = Vtxen_high \end{array}$		-35	-5		
Coupling of DCS Tx output to Receive RF output pad ³	CDCS_Tx-Rx_f0	$0 \text{ dBm} \le \text{Pout} \le 31 \text{ dBm}$	—	0	5	dBm	
Spurious	Spur	All combinations of the following parameters: $V_{RAMP} = controlled^2$ $P_{IN} = min. to max.$ $3.1 V \le Vcc \le 4.8 V$ $-20 °C \le T_{CASE} \le +85 °C$ Load VSWR = 12:1, all phase angles	No para	No parasitic oscillation > –36 dBm			
Load Mismatch	Load	All combinations of the following parameters: $V_{RAMP} = controlled^2$ $P_{IN} = min. to max.$ $3.1 V \le Vcc \le 4.8 V$ $-20 °C \le T_{CASE} \le +85 °C$ Load VSWR = 20:1, all phase angles	No mo	No module damage or permanent degradation			
Rx Band Spurious	Rx_spur	At f_0 + 20 MHz (1805 MHz to 1880 MHz) RBW = 100 kHz Vcc = 3.5 V TCASE = +25 °C 0 dBm \leq Pout \leq 31 dBm	_	-83	-78	dBm	
		925 MHz to 960 MHz RBW = 100 kHz Vcc = 3.5 V TCASE = $+25$ °C 0 dBm \leq Pout ≤ 31 dBm	_	_	-87		
Power Control Dynamic Range	PCdr		35	50		dB	

Table 7. SKY77550 Electrical Specifications ¹ (2 of 3)

	[0	continued] <i>DCS1800 (</i>	Tx_HB) Mode ($f = 1710$ MHz to 1785 MHz, -1 dBm $\le P_{IN} \le 5$	dBm)			
Pa	arameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Power Control Variation	trol Control Level 0	PCv	$\label{eq:VBATT} \begin{array}{l} V_{BATT} = 3.5 \text{ V} \\ 30 \text{ dBm} \leq Pout \leq 31 \text{ dBm} \\ T_{CASE} = +25 \ ^{\circ}C \end{array}$	-1.5	_	1.5	dB
			$30 \text{ dBm} \le \text{Pout} \le 31 \text{ dBm}$	-2.0		2.0	
Control Level 1-8		$\label{eq:VBATT} \begin{array}{l} V_{BATT} = 3.5 \text{ V} \\ 14 \text{ dBm} \leq P_{OUT} \leq 28 \text{ dBm} \\ T_{CASE} = +25 \ ^{\circ}C \end{array}$	-2.5	_	2.5		
			$14 \text{ dBm} \le P_{OUT} \le 28 \text{ dBm}$	-3.5		3.5	
	Control Level 9-13		$\label{eq:VBATT} \begin{array}{l} V_{BATT} = 3.5 \text{ V} \\ 4 \text{ dBm} \leq Pout \leq 12 \text{ dBm} \\ T_{CASE} = +25 \ ^{\circ}C \end{array}$	-3.5	_	3.5	
			4 dBm \leq Pout \leq 12 dBm	-4.5		4.5	
	Control Level 14-15			-4.5		4.5	
			$0 \text{ dBm} \le P_{\text{OUT}} \le 2 \text{ dBm}$	-5.5		5.5	
Power Control SI	lope	PCs	0 dBm to 31 dBm		_	250	dB/V
		DCS1	800 RECEIVE (<i>f</i> =1805 MHz to 1880 MHz) Rx Mode				•
Pa	arameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Frequency Rang	е	f	_	1805		1880	MHz
Insertion Loss, A	NT to Rx ^{5,3}	IL_Rx ⁵	$T_{CASE} = +25 \ ^{\circ}C$	_	1.2	1.5	dB
VSWR ANT, Rx ^{5,}	3	ΓΙΝ, ΓΟυτ	_		1.2:1	1.5:1	

Table 7. SKY77550 Electrical Specifications ¹ (3 of 3)

¹ Unless specified otherwise:

TCASE = -20 °C to max. operating temperature (see Table 2); RL = 50 Ω ; pulsed operation with pulse width \leq 1154 µs and duty cycle \leq 2:8; 3.1 V \leq VCC \leq 4.8 V.

 2 VRAMP is calibrated to each PCL at TCASE = +25 °C, VBATT = 3.5 V, PIN = 3 dBm, 50 Ω load.

 3 $\,$ Terminate all unused RF ports with 50 Ω loads

⁴ Max VRAMP = VRAMP @ POUT =31 dBm, 50 Ω load, TCASE +25 °C, VBATT = 3.5 V, PIN = 3 dBm

⁵ Rx1 and Rx2 are broadband receive ports and each supports the GSM850, GSM900, DCS, and PCS bands.

Table 8. SKY77550 Electrical Specifications¹ (1 of 3)

	PCS1900 (Tx_HB) Mode ($f = 1850$ MHz to 1910 MHz, -1 dBm \leq PiN \leq 5 dBm)					
Parameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Frequency Range	f	_	1850	_	1910	MHz
Input Power	Pin	_	-1		5	dBm
Analog Power Control Voltage	Vramp	_	0.2	_	1.6	٧
Power Added Efficiency	PAE	Vcc = 3.5 V $Pout = 31 dBm$ $PiN = 3 dBm$ $duty cycle 1:8$ $TcASE = +25 °C$	37	41	_	%

	[continued] PCS1900 (1	Tx_HB) Mode ($f = 1850$ MHz to 1910 MHz, -1 dBm $\leq H$	Pın ≤5 dBm)			
Parameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Supply Current @ Rated Power	lcc_31 dBm	Vcc = 3.5 V PIN = 3 dBm POUT = 31 dBm duty cycle 1:8 TCASE = $+25 \text{ °C}$	_	0.88	0.97	A
	lcc_28 dBm	Vcc = 3.5 V PIN = 3 dBm POUT = 28 dBm duty cycle 1:8 TCASE = $+25 \text{ °C}$	_	630	_	mA
Supply Current @ Minimum Power	lcc_0 dBm	Vcc = 3.5 V $P = 3 dBm$ $Pout = 0 dBm$ $duty cycle 1:8$ $Tcase = +25 °C$	_	45	55	mA
Harmonics	2fo to 7fo	$\begin{array}{l} BW = 3 \mbox{ MHz}, \\ 0 \mbox{ dBm} \leq \mbox{Pout} \leq 31 \mbox{ dBm} \\ \mbox{Vramp controlled}^2 \end{array}$	—	-40	-33	dBm
Mismatch Harmonics	2f0, 3f0	BW = 3 MHz VrAMP = MAX VrAMP4 VBATT = 3.5 V VSWR = 3:1 all phases TCASE = +25 °C			-33	dBm
Output Power	Роит	$V_{CC} = 3.5 V$ $T_{CASE} = +25 °C$ $P_{IN} = -1 dBm$	31.0	32.0	_	dBm
	POUT _MAX LOW VOLTAGE	$V_{CC} = 3.1 V$ $V_{RAMP} = MAX V_{RAMP}^4$ $-20 °C \le T_{CASE} \le +85 °C$ $P_{IN} = -1 dBm$	28.5	30.0	—	
	POUT _MAX HIGH VOLTAGE	$V_{CC} = 4.8 V$ $V_{RAMP} = MAX V_{RAMP}^4$ $-20 °C \le T_{CASE} \le +85 °C$ $P_{IN} = -1 dBm$	28.5	32.5	—	
Input VSWR	Гіл	0 dBm Pout \leq 31 dBm Vramp controlled ²	—	1.5:1	2.5:1	
Forward Isolation ³	Pout Rx	$\label{eq:Pin} \begin{array}{l} Pin = 5 \ dBm \\ Vramp \leq 0.1 \ V \\ Vsw_en = Vsw_en_high \\ TxEN = Vtxen_low \\ Rx2 \ Mode \end{array}$	_	-60	-53	dBm
	Pout_enabled_tx	$\label{eq:ramp} \begin{array}{l} Pin = 5 \ dBm \\ Vramp \leq 0.1 \ V \\ Vsw_en = Vsw_en_high \\ TxEN = Vtxen_high \\ \end{array}$	—	-35	-5	
Coupling of PCS Tx Output to Receive RF Output pad ³	CPCS_Tx-Rx_f0	$0 \text{ dBm} \le P_{0UT} \le 31 \text{ dBm}$	—	0	5	dBm
Spurious	Spur	All combinations of the following parameters: $V_{RAMP} = controlled^2$ $P_{IN} = min. to max$ $3.1 V \le V_{CC} \le 4.8 V$ $-20 °C \le T_{CASE} \le +85 °C$ Load VSWR = 12:1, all phase angles	No para	asitic oscilla	ition > −36 d	Bm

Table 8. SKY77550 Electrical Specifications ¹ (2 of 3)

Р	arameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units	
Load Mismatch		Load	All combinations of the following parameters: $V_{RAMP} = controlled^2$ $P_{IN} = min. to max.$ $3.1 V \le Vcc \le 4.8 V$ $-20 °C \le T_{CASE} \le +85 °C$ Load VSWR = 20:1, all phase angles		No module damage or permanent degradation			
Rx Band Spurious		Rx_spur	At $f_0 + 20$ MHz (1930 MHz to 1990 MHz) RBW = 100 kHz Vcc = 3.5 V Tcase = +25 °C 0 dBm \leq Pout \leq 31 dBm	_	-83	-78	dBm	
			$\begin{array}{l} 869 \mbox{ MHz to } 894 \mbox{ MHz} \\ \mbox{RBW} = 100 \mbox{ kHz} \\ \mbox{Vcc} = 3.5 \mbox{ V} \\ \mbox{Tcase} = +25 \mbox{ °C} \\ \mbox{0} \mbox{ dBm} \leq \mbox{Pout} \leq 31 \mbox{ dBm} \end{array}$	_		-87		
Power Control D	Dynamic Range	PCdr		35	50	—	dB	
Power Control Variation	Control Level 0	PCv	$ \begin{array}{l} V_{BATT}=3.5 \ V \\ 30 \ dBm \leq Pout \leq 31 \ dBm \\ T_{CASE}=+25 \ ^{\circ}C \end{array} $	-1.5	_	1.5	dB	
			30 dBm \leq Pout \leq 33 dBm	-2.0		2.0		
	Control Level 1-8		$\label{eq:VBATT} \begin{array}{l} VBATT = 3.5 \text{ V} \\ 14 \text{ dBm} \leq Pout \leq 28 \text{ dBm} \\ TCASE = +25 \ ^{\circ}C \end{array}$	-2.5	_	2.5		
			$14 \text{ dBm} \le P_{\text{OUT}} \le 28 \text{ dBm}$	-3.5		3.5		
	Control Level 9-13		$VBATT = 3.5 V$ $4 dBm \le Pout \le 12 dBm$ $TCASE = +25 °C$	-3.5	_	3.5		
			$4 \text{ dBm} \le \text{Pout} \le 12 \text{ dBm}$	-4.5	_	4.5		
	Control Level 14-15		$\label{eq:VBATT} \begin{array}{l} V_{BATT} = 3.5 \ V \\ 0 \ dBm \leq Pout \leq 2 \ dBm \\ T_{CASE} = +25 \ ^{\circ}C \end{array}$	-4.5		4.5		
			$0 \text{ dBm} \le Pout \le 2 \text{ dBm}$	-5.5		5.5		
Power Control S	Slope	PCs	0 dBm to 31 dBm	—	—	250	dB/V	
		PCS19	000 RECEIVE (f = 1930 MHz to 1990 MHz) = Rx Mode					
Р	arameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units	
				1000		1000		

Table 8. SKY77550 Electrical Specifications ¹ (3 of 3)

Parameter	Symbol	Test Condition	Minimum	Typical	Maximum	Units
Frequency Range	f	-	1930		1990	MHz
Insertion Loss, ANT to Rx ^{5,3}	IL_Rx ⁵	TCASE = +25 °C	_	1.2	1.5	dB
VSWR ANT, Rx ^{5,3}	Γιν, Γουτ	—	_	1.2:1	1.5:1	

¹ Unless specified otherwise:

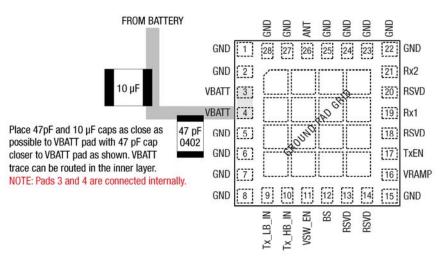
 $\mathsf{TCASE} = -20\ ^\circ\mathsf{C} \text{ to max. operating temperature (see Table 2); RL} = 50\ \Omega; \text{ pulsed operation with pulse width} \leq 1154\ \mu\text{s and duty cycle} \leq 2:8; 3.1\ V \leq V\mathsf{CC} \leq 4.8\ V.$

 2 VRAMP is calibrated to each PCL at TCASE = +25 °C, VBATT = 3.5 V, PIN = 3 dBm, 50 Ω load.

 3 $\,$ Terminate all unused RF ports with 50 Ω loads

⁴ Max VRAMP = VRAMP @ POUT =31 dBm, 50 Ω load, TCASE +25 °C, VBATT = 3.5 V, PIN = 3 dBm

⁵ Rx1 and Rx2 are broadband receive ports and each supports the GSM850, GSM900, DCS, and PCS bands.



Pad layout as seen from Top View looking through package.

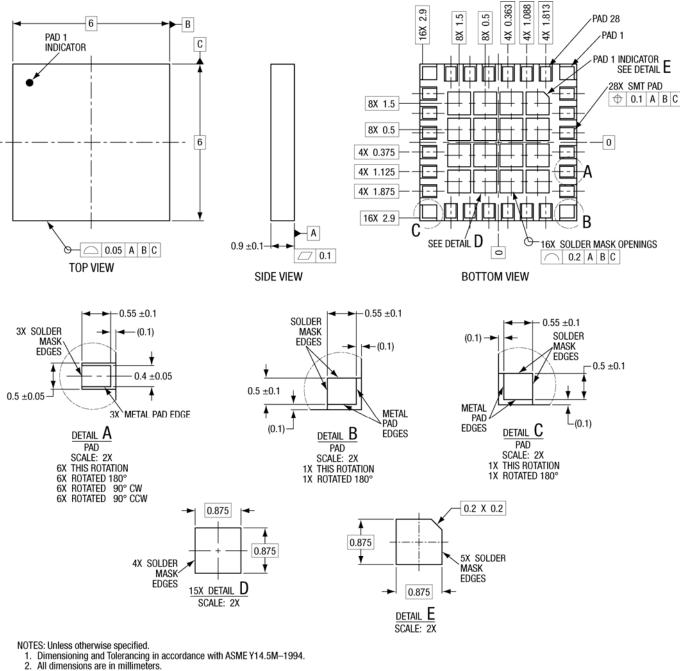
Figure 2. SKY77550 Application Schematic Diagram

201138_002

Package Dimensions

Figure 3 is a mechanical diagram of the pad layout for the SKY77550, a 28-pad leadless dual-band FEM. Figure 4 provides a recommended phone board layout footprint for the FEM to help

the designer attain optimum thermal conductivity, good grounding, and minimum RF discontinuity for the 50-ohm terminals.



Pad definitions per details on drawing.

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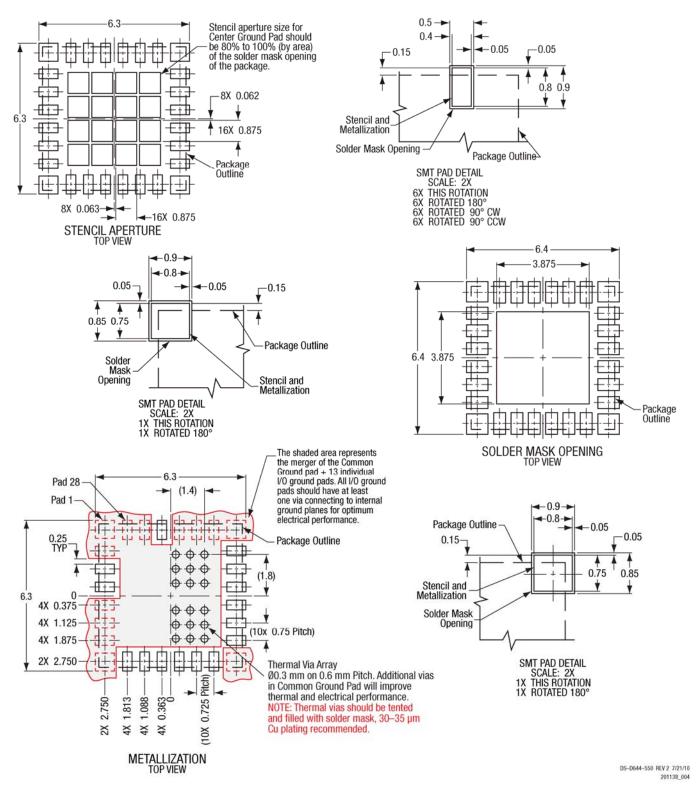
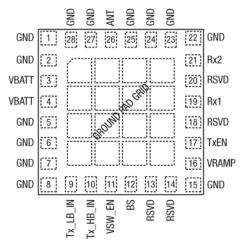


Figure 4. Phone PCB Layout Footprint for 6 mm x 6 mm, 28-Pad Package with Grid-Bottom Solder Mask – SKY77550 Specific.

Package Description

Figure 5 illustrates the device pad configuration and the numbering convention which starts with pad 1 at the lower left, as indicated and increments counter-clockwise around the package. Table 9 lists the pad names and the associated signal descriptions. Figure 6 interprets typical case markings.



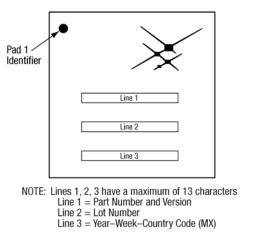
Pad layout as seen from Top View looking through package.

Figure 5. SKY77550 FEM Pad Configuration – 28-Pad Leadless (Top View)

Pad ¹	Name	Description
3, 4	VBATT	Battery input voltage (pads internally common)
9	Tx_LB_IN	RF input 824–915 MHz
10	Tx_HB_IN	RF input 1710–1910 MHz
11	VSW_EN	Control logic level selection/Standby control
12	BS	Band Select (mode control)
16	VRAMP	Analog power control voltage input
17	TxEN	Tx-Rx select (mode control)
19	Rx1	Broadband Receive Port
21	Rx2	Broadband Receive Port
26	ANT	RF_IN / RF_OUT to Antenna

Table 9. SKY77550 Pad Names and Signal Descriptions

¹ Pads 1, 2, 5–8, 15, 22–25, 27, 28 are ground pads. Pads 13, 14, 18, 20 are Reserved



201138_006

Figure 6. Typical Case Markings

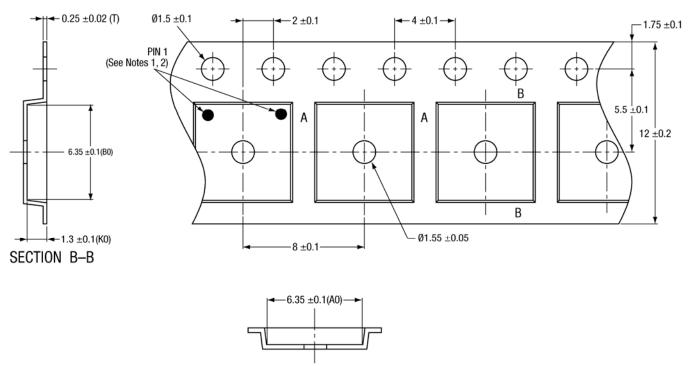
Package Handling Information

Because of its sensitivity to moisture absorption, this device package is baked and vacuum-packed prior to shipment. Instructions on the shipping container label must be followed regarding exposure to moisture after the container seal is broken, otherwise, problems related to moisture absorption may occur when the part is subjected to high temperature during solder assembly.

The SKY77550 is capable of withstanding an MSL3/260 °C solder reflow. Care must be taken when attaching this product, whether it is done manually or in a production solder reflow environment. If the part is attached in a reflow oven, the temperature ramp rate should not exceed 3 °C per second; maximum temperature should not exceed 260 °C. If the part is manually attached, precaution should be taken to insure that the part is not subjected to temperatures exceeding 260 °C for more than 10 seconds. For details on attachment techniques, precautions, and handling procedures recommended by Skyworks, please refer to Skyworks Application Note: *PCB Design and SMT Assembly/Rework*, Document Number 101752. Additional information on standard SMT reflow profiles can also be found in the JEDEC *Joint Industry Standard J-STD-020*.

Production quantities of this product are shipped in the standard tape-and-reel format (Figure 7).

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SECTION A-A

NOTES:

- 1. PIN 1 ORIENTATION IS "TOP LEFT" ONLY FOR RFLGA & MCM PRODUCTS LISTED BELOW:
 - SKY73022-21 SKY73022-31
 - SKY73023-21 SKY73023-31
- 2. PIN 1 ORIENTATION IS "TOP RIGHT" FOR ALL 6 x 6 mm RFLGA & MCM PRODUCTS EXCEPT THOSE LISTED IN NOTE 1 ABOVE.
- 3. CARRIER TAPE IS BLACK CONDUCTIVE POLYCARBONATE OR POLYSTYRENE.
- 4. COVER TAPE IS TRANSPARENT AND CONDUCTIVE.
- 5. ESD-SURFACE RESISTIVITY IS ≤ 1 X 10¹⁰ OHMS/SQUARE PER EIA, JEDEC TNR SPECIFICATION.
- 6. ALL DIMENSIONS ARE IN MILLIMETERS.

CARRIER TAPE OVERMOLD MCM/RFLGA 6 x 6 x 0.85 / 1.1 mm 80DY SIZE -1936 201138_008

Figure 7. Dimensional Diagram for Carrier Tape Body Size 6 mm x 6 mm x 0.85 / 1.1 mm - MCM

Electrostatic Discharge (ESD) Sensitivity

To avoid ESD damage, both latent and visible, it is very important that the product assembly and test areas follow the ESD handling precautions listed below.

- Personnel Grounding
 - Wrist Straps
 - Conductive Smocks, Gloves and Finger Cots
 - Antistatic ID Badges
- Protective Workstation
 - Dissipative Table Top
 - Protective Test Equipment (Properly Grounded)
 - Grounded Tip Soldering Irons
 - Solder Conductive Suckers
 - Static Sensors

- Facility
 - Relative Humidity Control and Air Ionizers
 - Dissipative Floors (less than 109 Ω to GND)
- Protective Packaging and Transportation
 - Bags and Pouches (Faraday Shield)
 - Protective Tote Boxes (Conductive Static Shielding)
- Protective Trays
- Grounded Carts
- Protective Work Order Holders

Ordering Information

Model Number	Manufacturing Part Number	Product Revision	Package	Operating Temperature
SKY77550	SKY77550		MCM 6 mm x 6 mm x 0.9	-20 °C to +85 °C

Revision History

Revision	Date	Description
A	October 27, 2009	Initial Release – Advance Information
В	November 9, 2009	Revise: Figure 4
C	April 11, 2010	Revise: Description (p1); Tables 2–8
D	May June 14, 2010	Revise: Change Data Sheet status to "Preliminary" from "Advance"; Description, Features list (p1); Figure 2; Tables 4–9; References
E	September 8, 2010	Revise: Features list (p1); Tables 4–8; Figures 4, 7

References

Skyworks Application Note: PCB Design and SMT Assembly/Rework, Document Number 101752

Skyworks Application Note: iPAC[™] Peak Output Power Calibration, Document Number 103180

Skyworks Application Note: SKY77550 BiFET iPAC™ Front-End Module – Implementation, Document Number 201287

Standard SMT Reflow Profiles: JEDEC Standard J-STD-020

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